

FREQUENCY-SELECTIVE NANOSTRUCTURED PLASMONIC ABSORBER BY HIGHLY LOSSY INTERFACE MODE

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Abstract—We report on an existence of a highly lossy interface mode (HLIM) in a designed plasmonic nanostructure for perfect absorption of the incident optical waves. Interactions between the single thin-metallic-layer (*TML*) and slits arrays for excitation of the HLIM in the proposed plasmonic absorber are investigated, and eigenfrequency formula for the HLIM is derived. Analytical and numerical results show that the HLIM is frequency-selective, opens a narrow and steep absorption band in photonic stopband of the slits arrays. Due to the HLIM lossy characteristic, surface plasmon polaritons are significantly trapped at the *TML* interface with absorption close to 100%.

1. INTRODUCTION

Currently, the “bodies” with high absorption properties has played an important role in modern science and nanotechnologies for their useful applications such as thermal detectors [1, 2], nanoelectronic power sources [3], microbolometers [4], time-reversed lasers [5], and solar energy conversion [6, 7]. The techniques to realize the high absorption attracts increasing attentions. It was shown that low-density vertically aligned carbon nanotube arrays can be engineered

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to have an extremely low index of refraction, and the light wave impinging on it were totally absorbed [8]. Kravets et al. experimentally demonstrated that metal nanoparticles embedded in a dielectric matrix can strongly absorb light above 90% for a broad angle of incidence in visible-near infrared range [9]. Based on an anisotropic perfectly impedance-matched negative-index material, Avitzour et al. theoretically designed a wide-angle infrared perfect absorber with potential applications for infrared imaging and coherent thermal sources [10]. Another promising candidate to obtain high absorption is metamaterials which was first proposed in 2008 by Padilla's group who had demonstrated that perfect absorption was possible by properly engineering metamaterials' electric and magnetic responses to satisfy the impedance match [11]. Metamaterial absorber is a hot research topic nowadays, and various kinds of devices have emerged such as wide angle terahertz absorber [12, 13], millimeter-wave range absorber [14], polarization-insensitive absorber [15–17], wide-angle and polarization-independent absorber in optical frequency range [18], and dualband terahertz absorber [19–21].

An absorber with a broad or narrow bandwidth is both necessary in practical applications. The former can provide strong absorption of sunlight in entire solar bandwidth [22–24]. The latter has significant applications in selective thermal emitters [25, 26], all-optical switch [27], surface plasmon resonance sensor [28], and hyper spectral-single pixel imaging [29], etc.

In this paper, with excitation of a novel highly lossy interface mode (HLIM) by coupling a single thin-metallic-layer (*TML*) to slit arrays in a two-dimensional metal-dielectric-metal (*MDM*) nanostructure, we propose a frequency selective plasmonic absorber with tunable and narrow bandwidth. The paper is organized as follows. In Section 2, the plasmonic absorber structure is presented. Transmission matrix model to investigate its optical properties is established, and eigenfrequency formula for the HLIM is analytically derived. In Section 3, with transmission matrix method (TMM) and finite-difference time-domain (FDTD) method, optical spectra and field distributions for the plasmonic absorber are demonstrated, and characteristics of the HLIM are addressed. In Section 4, dependence of structure parameters on absorption spectra of the plasmonic absorber are investigated. The reflection dip depends very sensitively on the dielectric surrounding, generating a sensitivity of 1100 nm/RIU which is about two times higher than the recently reported nanostructured sensors based on metamaterials [30, 31], nanoparticles [32], and localized surface plasmon resonant [33] Finally, conclusions are made in Section 5.

2. STRUCTURE MODEL AND ANALYSIS METHOD

The plasmonic absorber under study is schematically shown in Fig. 1. A two-dimensional *MDM* structure is composed of a dielectric core surrounded by two semi-infinite metallic claddings. A *TML* with thickness of L_m followed by slit arrays are inserted in the core. The width of the *MDM* core is w_1 , and the distance between the *TML* to the first slit is L . There are N slits in the slit arrays, depth and width for each slit is D and w_2 , respectively, and distance between each slit is L . The media at the left and right side of the *TML* are dielectrics *A* and *B* with refractive index of n_A and n_B , respectively. In our design, the metal is assumed to be gold whose permittivity can be characterized by Drude model of [25]

$$\varepsilon_m = 1 - \frac{\omega_p^2}{\omega^2 + i\omega\gamma}, \quad (1)$$

where $\omega_p = 1.37 \times 10^{16}$ rad/s and $\gamma = 1.22 \times 10^{14}$ rad/s are plasma frequency and damping constant, respectively. In the FDTD calculation, the waveguide mode source is emitted at the left waveguide. The structure reflection is $R = |S_{11}|^2$, transmission is $T = |S_{21}|^2$, and the absorption is $A = 1 - R - T$. Here, the S_{11} and S_{21} are the reflection coefficient and transmission coefficient, respectively.

When a transverse magnetic polarized optical wave is illuminated

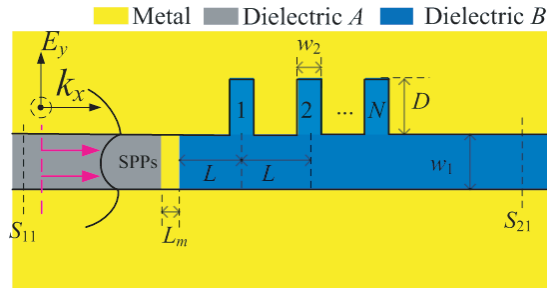


Figure 1. Schematic diagram of the proposed plasmonic absorber with a *TML* and slits arrays inserted in the core of a two-dimensional *MDM* structure. The yellow, cyan, and blue regions represent the metal, dielectric *A*, and dielectric *B*, respectively. The w_1 , L_m , and L denote, respectively, width of the *MDM* core, thickness of the *TML*, and distance between the *TML* and the first slit. The distance between each slit is L , and there are N slits with each having a depth of D and width of w_2 , respectively.

to the *MDM* structure, surface plasmon polaritons (SPPs) with relatively long propagation length and high confinement are excited [34], which can find wide applications such as nanolasers [35], waveguide [36, 37], all-angle negative refraction waveguides [38], nonlinear nanofocusing systems [39], etc.. In the structure shown in Fig. 1, the excited SPPs are confined to propagate in the dielectric *A* and travel to the *TML*. When the SPPs reach the *TML*, successively, they penetrate it and transmit to the dielectric *B* and the slit arrays. Aim to reveal how near-unity absorption is generated in above physical processes, we establish a transfer matrix model. At the left and right interfaces of the *TML*, the reflection and transmission occur with transfer matrixes of [40]

$$T_{l,r} = \tau_{l,r} \begin{pmatrix} 1 & \rho_{l,r} \\ \rho_{l,r} & 1 \end{pmatrix}, \quad (2)$$

where the T_l and T_r are transfer matrixes for the *A/TML* and *TML/B* interfaces, respectively. The $\tau_l = (n_l + n_m)/n_l/2$ and $\tau_r = (n_r + n_m)/n_m/2$, $\rho_l = (n_m - n_l)/(n_m + n_l)$, and $\rho_r = (n_r - n_m)/(n_r + n_m)$. Here, the n_l and n_r are effective refractive index of the SPPs propagating in the dielectrics *A* and *B*, respectively, and the n_m is the refractive index of the metal. The transfer matrixes for the SPPs propagating in the *TML* with length of L_m and the dielectric *B* with distance of L can be respectively described as

$$T_{TML} = \begin{pmatrix} e^{-ik_0 n_m L_m} & 0 \\ 0 & e^{ik_0 n_m L_m} \end{pmatrix}, \quad (3)$$

$$T_B = \begin{pmatrix} e^{-ik_0 n_r L} & 0 \\ 0 & e^{ik_0 n_r L} \end{pmatrix}. \quad (4)$$

Here, k_0 is propagation constant of optical wave in air.

Transmittance of the *MDM* waveguide coupled to a single slit can be described using the analogy between single-mode *MDM* waveguides and microwave transmission lines [41]. With this analogy, each slit in Fig. 1 is equivalent to an open-circuited transmission line with effective characteristic impedance described by $z_{slit} = z_s(z_L - iz_s \tan(\varphi))/(z_s - iz_L \tan(\varphi))$, where the $z_s = k_2 w_2 / \varepsilon_0 \varepsilon_B \omega$, $z_L = (\varepsilon_B / \varepsilon_m)^{0.5} z_s$, and $\varphi = k_2 D$. Here, the k_2 is propagation constant of SPPs in the slit. With above simplified transmission-line model, the transfer matrix for each slit is expressed as [36]

$$T_{slit} = \begin{pmatrix} 1 + \frac{z_{slit}}{2z_{MDM}} & \frac{z_{slit}}{2z_{MDM}} \\ -\frac{z_{slit}}{2z_{MDM}} & 1 - \frac{z_{slit}}{2z_{MDM}} \end{pmatrix}. \quad (5)$$

Here, the $z_{MDM} = k_1 w_1 / \varepsilon_0 \varepsilon_B \omega$ is characteristic impedance of the *MDM* line, and the k_1 is propagation constant of SPPs in the *MDM* core.

With the Eqs. (1) to (5) described above, the total transfer matrix for the SPPs propagating along the *TML* and the slit arrays can be achieved as

$$T = T_l T_{TML} T_r (T_B T_{slit})^N = \begin{pmatrix} M_{11} & M_{12} \\ M_{21} & M_{22} \end{pmatrix}. \quad (6)$$

The Eq. (6) analytically gives us optical properties of the proposed structure. Its reflection coefficient, transmission coefficient, and absorption coefficient can be obtained as $r = M_{21}/M_{11}$, $t = 1/M_{11}$, and $A = 1 - |r|^2 - |t|^2$, respectively.

To guarantee the proposed structure with a high absorption, neither reflection nor transmission should happen. If we define that

$$T_2 \equiv (T_B T_{slit})^N = \begin{pmatrix} A_2 & B_2 \\ C_2 & D_2 \end{pmatrix}, \quad (7)$$

the structure reflection can be thereby expressed as

$$R = \left| \frac{M_{21}}{M_{11}} \right|^2 = \left| \frac{(\rho_l + \rho_r e^{i2k_0 n_m L_m}) A_2 + (\rho_l \rho_r + e^{i2k_0 n_m L_m}) C_2}{(1 + \rho_l \rho_r e^{i2k_0 n_m L_m}) A_2 + (\rho_r + \rho_l e^{i2k_0 n_m L_m}) C_2} \right|^2. \quad (8)$$

For the absorber, the numerator in Eq. (8) should be zero. Therefore, by applying some algebraic manipulations we can derive that

$$R_1 R_2 = 1, \quad (9)$$

where the $R_2 = |C_2/A_2|^2$ is reflection for the *MDM* structure with slit arrays are in the core (i.e., the *TML* is not in the *MDM* structure shown in Fig. 1), and the R_1 is determined by $R_1 = |\rho_l \rho_r + \exp(i2k_0 n_m L_m)|^2 / |\rho_l + \rho_r \exp(i2k_0 n_m L_m)|^2$. The eigenfrequency of Eq. (9) corresponds to an interface mode similar to the traditional optical Tamm states [42–44]. The difference is that optical Tamm states are lossless, while the interface mode here is highly lossy.

Now we consider solution of Eq. (9). Provided that $L = 180$ nm, $D = 200$ nm and $n_B = 1$, the R_2 versus frequency with different slit cell N is plotted in Fig. 2(a). Clearly, a photonic stopband is generated, where reflection reaches its maximum. However, due to the SPP losses it is smaller than 1. In order to realize Eq. (9), R_1 should be larger than 1. Variation of the R_1 to frequency at different L_m is shown in Fig. 2(b). It depicts that that R_1 increases with frequency, and especially, by adjusting L_m it can be tuned to be larger than 1. Above two characteristics enable us to satisfy Eq. (9) at a certain frequency locating in the photonic stopband by utilizing proper

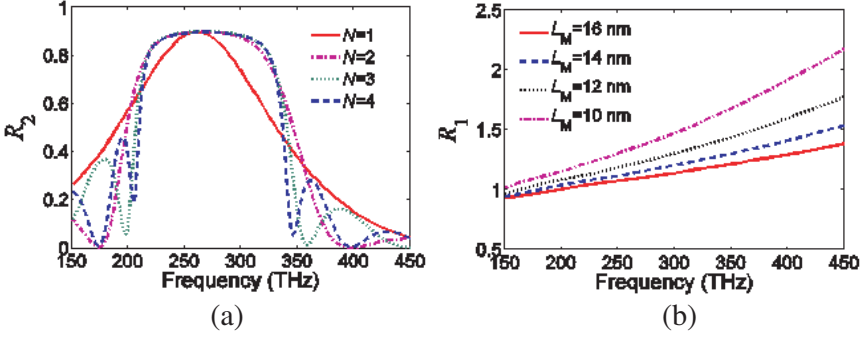


Figure 2. (a) R_2 versus frequency with different slit cell N . (b) Variation of R_1 to frequency and L_M . The other structure geometric parameters are: $L = 180$ nm, $D = 200$ nm, $w_1 = 60$ nm, $w_2 = 60$ nm, $n_A = 1$, and $n_B = 1$.

structure geometric parameters. In this case, no reflection occurs. Meanwhile, since the frequency is in the photonic stopband, there is no transmission either. As a result, perfect absorption happens here.

3. EXISTENCE OF THE HLIM AND SIMULATION RESULTS

Aim to show feasibility of the Eq. (9) for giving eigenfrequency of the proposed plasmonic absorber, the $R_1 R_2 - 1$ versus frequency is calculated in Fig. 3(a) with $w_1 = 60$ nm, $w_2 = 60$ nm, $L_m = 14$ nm, $L = 180$ nm, $D = 200$ nm, $N = 1$, $n_A = 1$, and $n_B = 1$. It is noted that the $R_1 R_2 - 1$ reaches its minimum of zero at frequency of 261.4 THz. The red solid line in Fig. 3(a) shows the structure reflection spectrum analytically calculated by the Eq. (6). It demonstrates that a sharp zero dip appears at the position when $R_1 R_2 - 1$ equals zero. The reflection spectrum is also numerically performed by FDTD method and depicted in Fig. 3(a) with blue circles. Obviously, the analytical results agree well with the FDTD results, which validate our TMM model for dealing with the proposed plasmonic absorber. The structure transmission (T) and absorption (A) spectra are calculated and plotted in Fig. 3(b). As predicted in the second section, the transmission is almost zero in the photonic stopband, and perfect absorption close to 100% is achieved at the frequency of the reflection dip. We can also observe that the plasmonic absorber possesses of absorption with steep band and narrow full-width at half-maximum (FWHM), which is attractive for sensing and imaging applications.

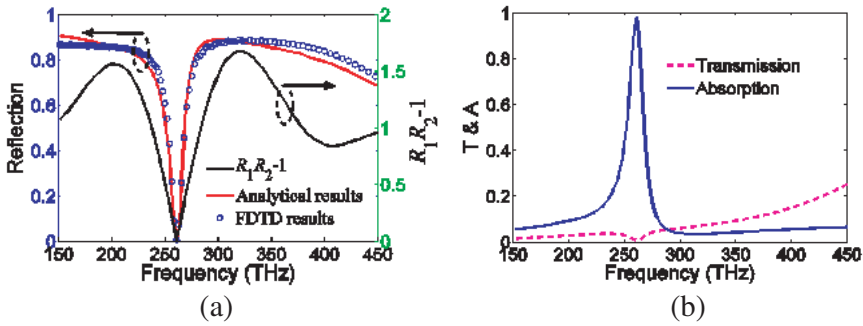


Figure 3. (a) Reflection spectrum of the plasmonic absorber and profile of the $R_1 R_2 - 1$. The red solid line and blue circles represent the reflection obtained by the Eq. (6) and FDTD method, respectively. (b) Transmission and absorption spectra of the plasmonic absorber. The structure geometric parameters are: $L_m = 14$ nm, $L = 180$ nm, $D = 200$ nm, $w_1 = 60$ nm, $w_2 = 60$ nm, $N = 1$, $n_A = 1$, and $n_B = 1$.

In order to reveal how *TML* interact with slit arrays to generate perfect absorption in the proposed plasmonic absorber, structure field distributions are demonstrated by two-dimensional FDTD method. In the calculations, the perfect matching layers are set along x and y directions at edges of the structure. The spatial sizes are $\Delta x = \Delta y = 2$ nm, and the temporal cell size is $\Delta t = \Delta x / (2c)$, where c is velocity of optical wave in vacuum. The source is continuous at eigenfrequency of 261.4 THz with amplitude of 1. Figs. 4(a) and (b) indicate that when the *TML* and slit are placed separately in the *MDM* structure, the SPPs are almost reflected. The former result arises from thickness of the *TML* approaching skin depth of the gold material, while the latter is due to the photonic stopband effect. When the slit is adjacent to the *TML* in the *MDM* structure as shown in Fig. 4(c), the Eq. (9) is satisfied, hence the SPPs pass through the *TML* without reflection. While the SPPs travel to the slit, they are reflected back to the *TML* and an interface mode is excited. Field amplitude of $|H_z|^2$ along $y = 0$ μm (i.e., the black dashed line in Fig. 4(c)) is plotted in Fig. 4(d), where the left and right perpendicular pink dotted line represent position of the *TML/B* interface and slit center, respectively. It demonstrates that the interface mode has a strong local-field enhancement at the *TML/B* interface. Due to metallic loss of the *TML* it is highly absorbed, decaying dramatically to zero at the *A/TML* interface and exponentially to zero at the slit center.

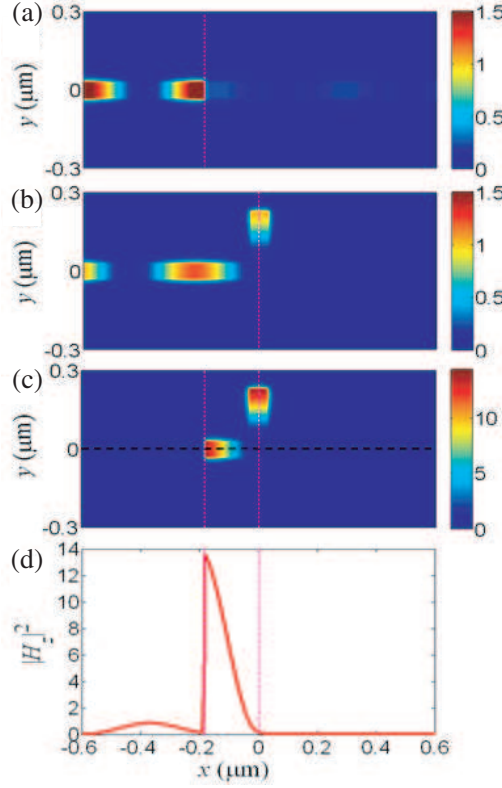


Figure 4. Field distributions of $|H_z|^2$ for the MDM structure at 261.4 THz with (a) single TML and (b) single slit in the MDM core. (c) The $|H_z|^2$ for the MDM structure at 261.4 THz when the TML and the slit are both inserted in the MDM core. The black dashed line illustrates $y = 0$ μm . (d) The $|H_z|^2$ along the $y = 0$ μm . Here, the left and right perpendicular pink dotted lines represent position of TML interface and slit center, respectively.

4. TUNABILITY OF THE PLASMONIC ABSORBER

In this section, tunability of the plasmonic absorber is investigated. As described in the Eq. (9), since the HLIM is frequency-selectively occurring in photonic stopband of the slit arrays, the absorption peak can be tuned by changing the structure geometric parameters to influence the photonic stopband. In our plasmonic absorber, the slit arrays with N cells can be assumed infinite periodic structures obey the Bloch-Floquet theorem. Each unit cell consists of a transmission

line with length L and a susceptance. At the position of the n th unit cell, the column vector for the voltage fulfills

$$\hat{T} \begin{pmatrix} V_n^+ \\ V_n^- \end{pmatrix} = e^{\pm ik^{Bloch}L} \begin{pmatrix} V_n^+ \\ V_n^- \end{pmatrix}. \quad (10)$$

Here, V_n^+ and V_n^- are the forward and backward voltage in the n th unit cell, respectively, and k^{Bloch} is the Bloch-wave vector. The \hat{T} is translation operator across single unit cell determined by

$$\hat{T} = T_B T_{slit} = \begin{pmatrix} e^{-ik_0 n_r L (1 + \frac{z_{slit}}{2z_{MDM}})} & e^{-ik_0 n_r L \frac{z_{slit}}{2z_{MDM}}} \\ -e^{ik_0 n_r L \frac{z_{slit}}{2z_{MDM}}} & e^{ik_0 n_r L (1 - \frac{z_{slit}}{2z_{MDM}})} \end{pmatrix}. \quad (11)$$

Therefore, the Bloch-wave dispersion relation for the slit arrays can be written as

$$\cos(k^{Bloch}L) = \frac{1}{2}(\hat{T}(1,1) + \hat{T}(2,2)). \quad (12)$$

When the magnitude of Eq. (12) is more than or equal to unity, the photonic stopband is generated. Dispersion curves of the $k^{Bloch}L/\pi$ versus the slit length L and depth D are plotted in Figs. 5(a) and (b), respectively. The black regions represent the photonic stopband of the slit arrays. Obviously, its position can be effectively tuned by varying L or D .

When $L_m = 14$ nm, $D = 200$ nm, $w_1 = 60$ nm, $w_2 = 60$ nm, $N = 3$, $n_A = 1$, and $n_B = 1$, the absorption spectra for the plasmonic absorber with $L = 130$, 180, and 230 nm are depicted in Fig. 6(a),

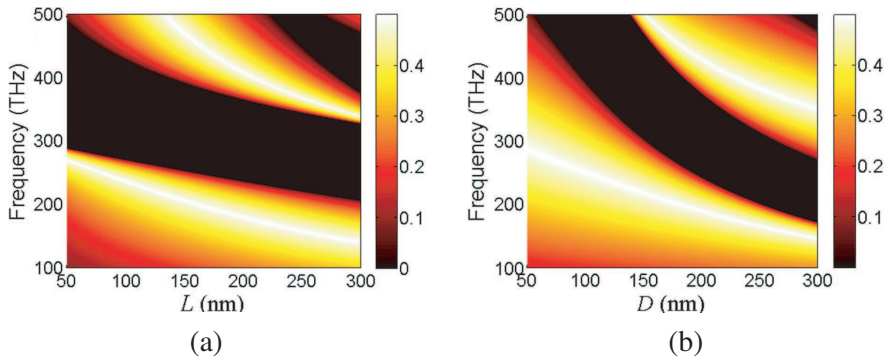


Figure 5. Dispersion for the SPPs propagating in slit arrays in *MDM* structure. (a) The $k^{Bloch}L/\pi$ versus frequency and L with $D = 200$ nm. (b) The $k^{Bloch}L/\pi$ versus frequency and D with $L = 180$ nm. The black region indicates the photonic stopband. The other structure geometric parameters are $w_1 = 60$ nm, $w_2 = 60$ nm, and $n_B = 1$.

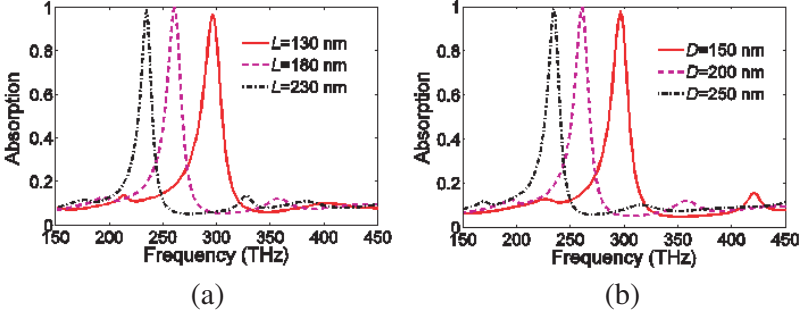


Figure 6. Dependence of the absorption spectra on (a) L when $D = 200$ nm and (b) D when $L = 180$ nm, respectively. The other structure geometric parameters are $L_m = 14$ nm, $w_1 = 60$ nm, $w_2 = 60$ nm, $N = 3$, $n_A = 1$, and $n_B = 1$.

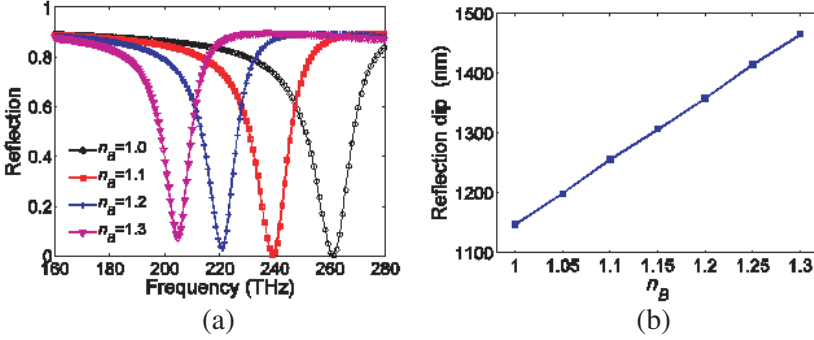


Figure 7. (a) Reflection spectra of the plasmonic absorber with different dielectric B . (b) Refractive index n_B sensitivity to the reflection dip.

respectively. It shows that the absorption peak behaves a red-shift by increasing the L . A same phenomenon is also observed by increasing the D as shown in the Fig. 6(b), where the absorption spectra at $D = 150, 200$, and 250 nm with $L = 180$ nm are plotted, respectively. The physical reason for the redshift of the absorption peak can be easily understood from Fig. 6. Increasing L or D will vary the photonic stopband to the lower frequency and correspondingly, the HLIM will be shifted to the lower frequency. Above results demonstrates that the proposed plasmonic absorber is highly flexible and its absorption peak can be effectively tuned by changing the structure size.

Dependence of the refractive index n_B on the reflection spectra of the plasmonic absorber is also studied as shown in Fig. 7(a). It is

noteworthy that the position of the reflection dip can be substantially influenced by the materials in the plasmonic absorber. When the n_B is changed from 1.0 to 1.1, 1.2, and 1.3, the reflection dip varies significantly from 261.4 to 238.9, 220.8, and 204.6 THz, respectively. This property can be well utilized for sensing applications. In Fig. 7(b), the wavelength of reflection dip versus the n_B is plotted, with a sensitivity (slop) about 1100 nm/RIU. This value is two times higher than the current nanosensors based on the metamaterials [30,31], nanoparticles [32], and localized surface plasmon resonant [33] whose sensitivity is less than 500 nm/RIU. Therefore, the proposed plasmonic absorber can be used as an excellent sensing platform for chemical and biochemically relevant molecules such as live glucose [45] viruses [46], proteins, and DNA.

5. CONCLUSION

In conclusion, we have proposed and investigated a new kind of nanostructured plasmonic absorber based on the excitation of HLIM in a two-dimensional *MDM* structure. The transfer matrix model is established to analytically investigate the optical properties of the plasmonic absorber, which shows that the eigenfrequency of HLIM is frequency-selectively occurring in photonic stopband of the slits arrays with a narrow band response. The FDTD method is utilized to numerically study the field distributions of the plasmonic absorber. The results demonstrate that due to interaction between *TML* and slit arrays, the HLIM is excited at the *TML* interface with a strong local-field enhancement, and totally absorbed here because of the *TML* metallic losses. Dependence of structure geometric parameters on absorption spectrum is also investigated. It demonstrates that the absorption peak can be effectively tuned by varying L or D . Meanwhile, it depends very sensitively on the dielectric surrounding, yields sensitivity as high as 1100 nm/RIU. The proposed nanostructured plasmonic absorber possesses of a tunable and narrow absorption band, which may find potential applications such as in biomedical sensing, thermal emitting, and all-optical integrated photonic circuits.

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